

Micro Commercial Components

Micro Commercial Components 20736 Marilla Street Chatsworth CA 91311 Phone: (818) 701-4933 (818) 701-4939 Fax:

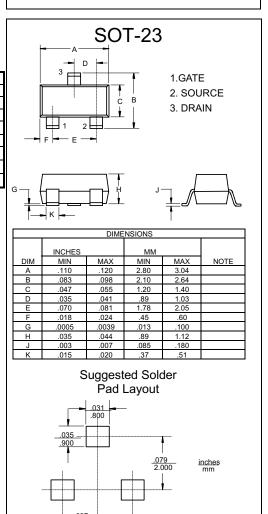
SI2303

Features

- -30V,-2.6A, R_{DS(ON)}=130m Ω @V_{GS}= -10V -30V,-2.0A, R_{DS(ON)}=180m Ω @V_{GS}= -4.5V
- High dense cell design for extremely low R_{DS(ON)}
- Rugged and reliable
- Lead free product is acquired
- SOT-23 Package
- Marking Code: S3
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0 and MSL Rating 1 Maximum Ratings @ 25°C Unless Otherwise Specified

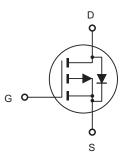
Symbol	Parameter	Rating	Unit	
V _{DS}	Drain-source Voltage	-30	V	
ID	Drain Current-Continuous	-3	А	
I _{DM}	Drain Current-Pulsed ^a	-10	A	
V _{GS}	Gate-source Voltage	±20	V	
PD	Total Power Dissipation	0.25	W	
R∘JA	Thermal Resistance Junction to Ambient ^b	500	°C/W	
TJ	Operating Junction Temperature	-55 to +150	°C	
T _{STG}	Storage Temperature	-55 to +150	°C	

P-Channel Enhancement Mode Field Effect Transistor



.037 .950

Internal Block Diagram



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Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Parameter	Symbol	Test Condition	Min	Тур	Max	Units	
Off Characteristics							
Drain-Source Breakdown Voltage	BVDSS	$V_{GS} = 0V$, $I_D = -10\mu A$	-30			V	
Zero Gate Voltage Drain Current	IDSS	VDS = -30V, VGS = 0V			-1	μA	
Gate Body Leakage Current, Forward	IGSSF	Vgs = 20V, Vds = 0V			100	nA	
Gate Body Leakage Current, Reverse	Igssr	Vgs = -20V, Vds = 0V			-100	nA	
On Characteristics ^c							
Gate Threshold Voltage	VGS(th)	Vgs = Vds, Id =-250µA	-1		-3	V	
Static Drain-Source On-Resistance	RDS(on)	Vgs = -10V, ID = -2.6A			130	mΩ	
		Vgs = -4.5V, ID = -2.0A			180	mΩ	
Forward Transconductance	gFS	VDS = -10V, ID = -1.7A		2.4		S	
Dynamic Characteristics ^d							
Input Capacitance	Ciss	VDS = -15V, VGS = 0V, f = 1.0 MHz		226		pF	
Output Capacitance	Coss			87		pF	
Reverse Transfer Capacitance	Crss	1 - 1.0 WHZ		19		pF	
Switching Characteristics ^d							
Turn-On Delay Time	td(on)			9	20	ns	
Turn-On Rise Time	tr	VDD = -15V, ID = -1A, VGEN = -10V, RG=6Ω,		9	20	ns	
Turn-Off Delay Time	td(off)	$RL=15\Omega$		18	35	ns	
Turn-Off Fall Time	tr	NL-1322		6	20	ns	
Total Gate Charge	Qg			5.8	10	nC	
Gate-Source Charge	Qgs	VDS = -15V, ID = -1.7A, VGS =-10V		0.8		nC	
Gate-Drain Charge	Qgd	VGS 10V		1.5		nC	
Drain-Source Diode Characteristics and Maximun Ratings							
Drain-Source Diode Forward Voltage $^{\circ}$	Vsd	Vgs = 0V, Is = -1.25A			-1.2	V	

Notes : a.Repetitive Rating : Pulse width limited by maximum junction temperature. b.Surface Mounted on FR4 Board, t < 10 sec. c.Pulse Test : Pulse Width < 300µs, Duty Cycle < 2%. d.Guaranteed by design, not subject to production testing.

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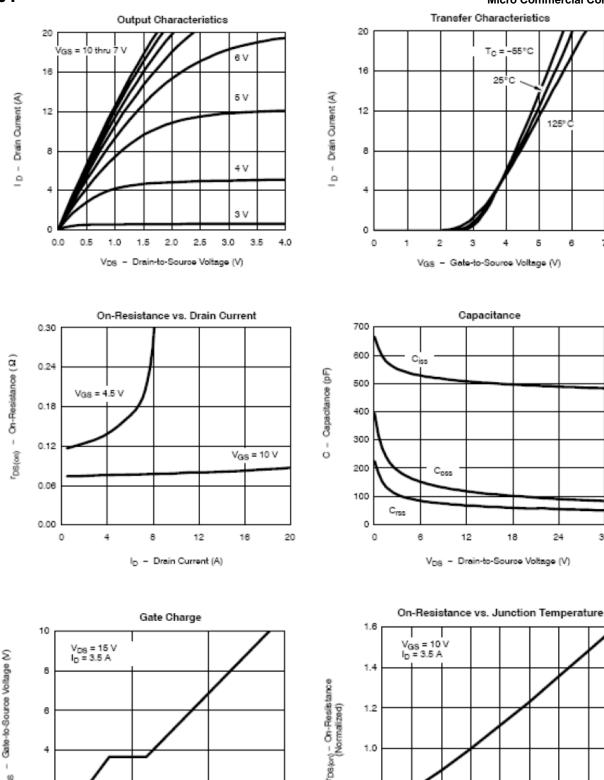
SI2303 Typical characteristics



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Revision: 1

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Qg - Total Gate Charge (nC)

0.8

0.6

-50

-25

0

25

50

T_J - Junction Temperature (° C)

75

100

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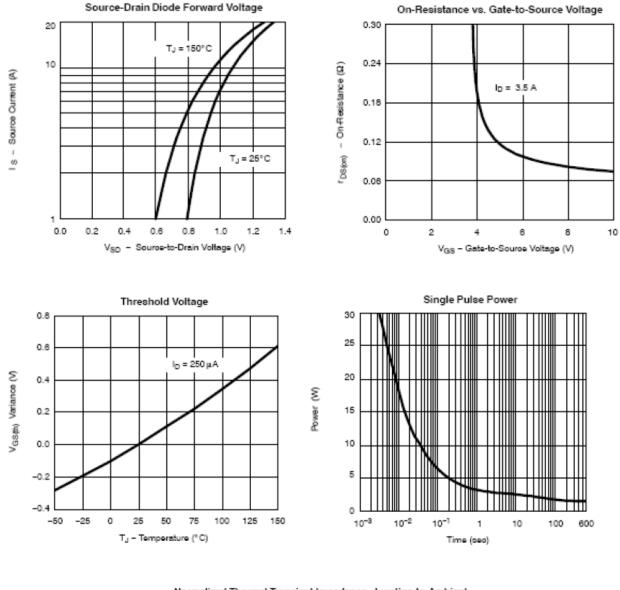
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SI2303

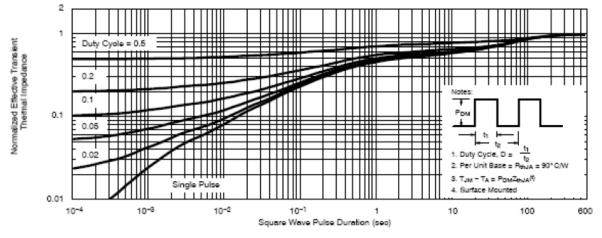
Typical characteristics



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Normalized Thermal Transient Impedance, Junction-to-Ambient



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Revision: 1



Ordering Information

Device	Packing		
(Part Number)-TP	Tape&Reel3Kpcs/Reel		

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